

Schotky Barrier Diode NSR0240MX2

Schottky barrier diodes are optimized for very low forward voltage drop and low leakage current and are used in a wide range of dc-dc converter, clamping and protection applications in portable devices. NSR0240MX2 in the X2DFN2 miniature package enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Very Low Forward Voltage Drop: 460 mV @ 100 mA
- Low Reverse Current: 0.2 μA @ 25 V VR
- 200 mA of Continuous Forward Current
- Very High Switching Speed
- Low Capacitance: CT = 7 pF
- NSxR0240MX2WT5G X2DFNW2 Wettable Flank Package for Optimal Automated Optical Inspection (AOI)
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

Markets

- Mobile Handsets & Notebook PCs
- Digital Camera and Camcorders
- Automotive Electronic Control Units
- GPS

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	40	V
Forward Current (DC)	IF	200	mA
Non-Repetitive Peak Forward Surge Current, Square Wave, 10 ms	I _{FSM}	3.0	Α
Repetitive Peak Forward Current, Square Wave, 1.0 ms, D.C. = 25%	I _{FRM}	1.0	Α
ESD Rating: Human Body Model Machine Model	ESD	Class Class	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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40 V SCHOTTKY BARRIER DIODE





X2DFN2 CASE 714AB



X2DFNW2 CASE 711BG RM

MARKING

DIAGRAM

RM

R = Specific Device Code M = Month Code

ORDERING INFORMATION

Device	Package	Shipping†
NSR0240MX2T5G	X2DFN2 (Pb-Free)	
NSR0240MX2WT5G	X2DFNW2 (Pb-Free)	8000 / Tape & Reel
NSVR0240MX2WT5G (In Development)	X2DFNW2 (Pb-Free)	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NSR0240MX2

THERMAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ T _A = 25°C	$egin{array}{c} R_{ hetaJA} \ P_D \end{array}$			400 300	°C/W mW
Junction and Storage Temperature Range	T _J , T _{stg}			-55 to +150	°C

^{1.} FR-4, 20 mm², 1 oz. Cu.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage (V _R = 25 V) (V _R = 40 V)	I _R		0.2 0.8	0.55 5.0	μΑ
Forward Voltage (I _F = 0.1 mA) (I _F = 1.0 mA) (I _F = 10 mA) (I _F = 100 mA) (I _F = 200 mA)	V _F		0.21 0.27 0.34 0.46 0.54	0.24 0.30 0.365 0.50 0.60	V
Total Capacitance (V _R = 1.0 V, f = 1 MHz)	СТ		7.0		pF

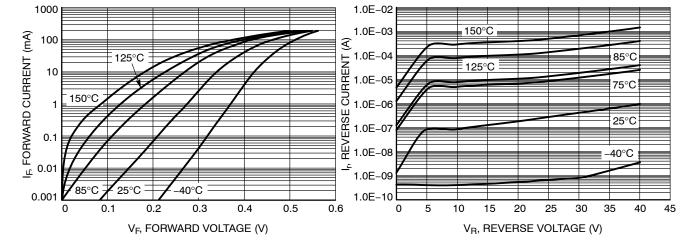


Figure 1. Forward Voltage

Figure 2. Leakage Current

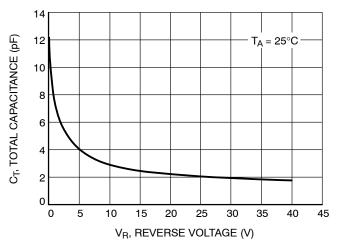


Figure 3. Total Capacitance



X2DFNW2 1.0x0.6, 0.65PCASE 711BG ISSUE C

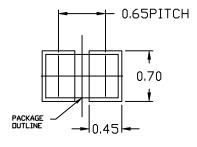
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NOTES:

-D1

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 APPLIES TO THE PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 FROM THE TERMINAL TIP.

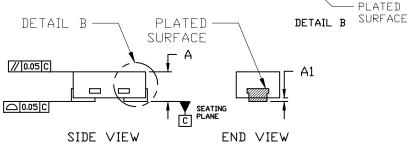
	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.34	0.37	0.40	
A1			0.05	
b	0.45	0.50	0.55	
D	0.90	1.00	1.10	
D1			0.05	
Ε	0.50	0.60	0.70	
e	0.65 BSC			
L	0.22 REF			
L1	0.24 0.285 0.34			

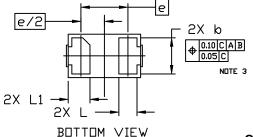


RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

2X 0.05 C PIN 1 REFERENCE TOP VIEW





GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

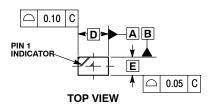
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DESCRIPTION:	X2DFNW2 1.0X0.6, 0.65P		PAGE 1 OF 1	

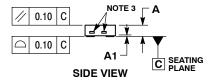
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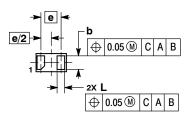


X2DFN2 1.0x0.6, 0.65P CASE 714AB **ISSUE B**

DATE 21 NOV 2017







BOTTOM VIEW

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. EXPOSED COPPER ALLOWED AS SHOWN.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.34	0.37	0.40	
A1		0.03	0.05	
b	0.45	0.50	0.55	
D	0.95	1.00	1.05	
Е	0.55	0.60	0.65	
е	0.65 BSC			
L	0.20	0.25	0.30	

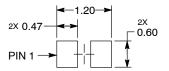
GENERIC MARKING DIAGRAM*



XX = Specific Device Code

M = Date Code

RECOMMENDED SOLDER FOOTPRINT*



DIMENSIONS: MILLIMETERS

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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